Devices

Am27S49/27S49A/29S49SA

8192x8 Generic Series IMOX™ Bipolar PROM

DISTINCTIVE CHARACTERISTICS

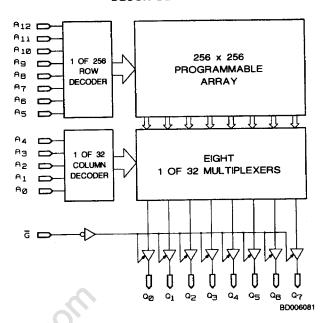
- Fast access time
- Platinum-Silicide fuses guarantee high reliability, fast programming and exceptionally high programming yields (typ > 98%)
- AC performance is factory tested utilizing programmed test words and columns
- Voltage and temperature compensation provides extremely flat AC performance over military range

GENERAL DESCRIPTION

The Am27S49 Series are high-speed, electrically programmable Schottky read-only memories, organized in 8192 x 8 configuration. After programming stored information is read on outputs Q0-Q7 by applying unique binary ad-

dresses to $A_0 - A_{12}$ and holding the Output Enable (\overline{G}) input LOW. When G is HIGH, Q0 - Q7 are in the OFF, or high-impedance state.

BLOCK DIAGRAM

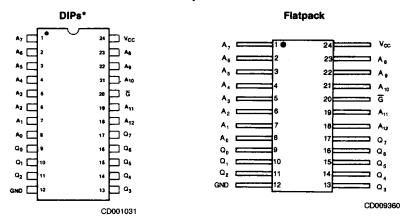


PRODUCT SELECTOR GUIDE

Address Time (ns) 25 30 40 45 55 55 6		Part Number	Am27S49SA		Am27S49A			Am27S49		
			25	25 30	40	45	55	55	65	
Operating COM'L MIL COM'L COM'L MIL COM'L N			COM'L	MIL	COM'L	COM'L	MIL	COM'L	MIL	
	7.0									
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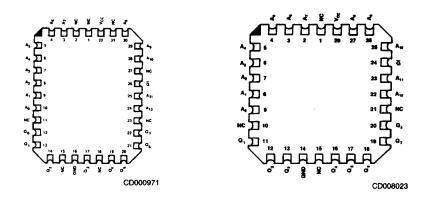
Rev. Amendment 04943 Issue Date: January 1989

CONNECTION DIAGRAMS Top View



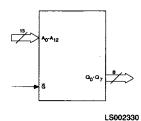
^{*}Also available in 24-pin Slim DIPs (Alternate Packaging Option Only); pinout is identical to standard DIPs.

LCCs



Note: Pin 1 is marked for orientation.

LOGIC SYMBOL

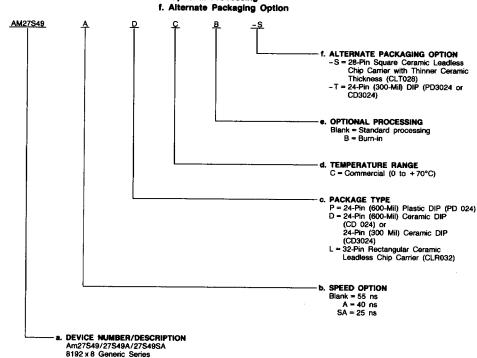


ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: a. Device Number

- a. Device Numberb. Speed Option (if applicable)
- c. Package Type
- d. Temperature Range
- e. Optional Processing



Valid Combinations

Valid Co	ombinations
AM27S49	DC, DCB, PC, PCB,
AM27S49A	LC, LCB, LC-S, LCB-S, DC-T, DCB-T, PC-T,
AM27S49SA	PCB-T

IMOX Bipolar PROM

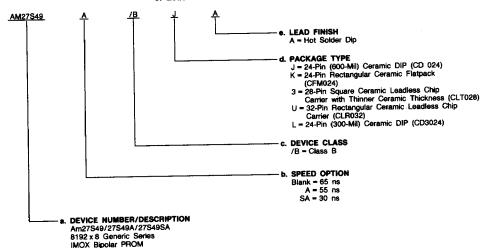
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released valid combinations, and to obtain additional data on AMD's standard military grade products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Device Class
- d. Package Type
- e. Lead Finish



Valid Combinations						
AM27S49						
AM27S49A	│ /BJA, /BKA, /B3A, │ /BUA, /BLA					
AM27S49SA	7					

Valid Combinations

Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests include Subgroups 1, 2, 3, 7, 8, 9, 10, and 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

A₀ - A₁₂ Address (Inputs)

The 13-bit field presented at the address inputs selects one of 8192 memory locations to be read from.

G Output Enable (Input, Active LOW)

Provides direct control of the Q-output three-state buffers.

Q₀ - Q₇ Data Output Port (Outputs, Three-State)

The outputs whose state represents the data read from the selected memory locations. These outputs are three-state buffers which when disabled, are in a floating or high-impedance state.

GENERIC PROGRAMMING INFORMATION

Advanced Micro Devices' Bipolar PROMs are members of a generic series incorporating common programming procedures. All parts in this series are produced with a fusible link at each memory location storing a logic LOW and can be

selectively programmed to a logic HIGH by applying appropriate voltages to the circuit.

See the AMD Bipolar/MOS Memories Data Book for detailed programming information.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature65 to +150°C
Ambient Temperature with
Power Applied55 to +125°C
Supply Voltage0.5 V to +7.0 V
DC Voltage Applied to Outputs
(Except During Programming)0.5 to +V _{CC} Max.
DC Voltage Applied to Outputs
During Programming
Output Current into Outputs During
Programming (Max Duration of 1 sec)
DC Input Voltage0.5 V to +5.5 V
DC Input Current30 to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices	
Ambient Temperature (TA)	0 to +75°C
Supply Voltage (V _{CC})	
Military (M) Devices*	
Case Temperature (T _C)	55 to +125°C
Supply Voltage (VCC)	

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military Product 100% tested at T_C = +25°C, +125°C, and

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test (Min.	Тур.	Max.	Unit					
VoH	Output HIGH Voltage	V _{CC} = Min., I _{OH} = -2.0 mA V _{IN} = V _{IH} or V _{IL}	2.4			v					
VOL	Output LOW Voltage	V _{CC} = Min., l _{OL} = 16 mA V _{IN} = V _{IH} or V _{IL}				<u> </u>	0.50	v			
VIH.	Input HIGH Level	Guaranteed Input Logical HIGH Voltage for All Inputs (Note 1)						V			
V _{IL}	Input LOW Level	Guaranteed Input Logical LOW Voltage for All Inputs (Note 1)					0.8	v			
4L	Input LOW Current	V _{CC} = Max., V _{IN} = 0.45 V				-250	μА				
lus Innet I	Input HIGH Current	V _{CC} = Max.	COM'L	V _{IN} = 5.0 V	<u> </u>						
'II'		VCC - Max.	MIL	V _{IN} = V _{CC}	Ī		40	μA			
Isc	Output Short-Circuit Current	V _{CC} = Max., V _{OUT} = 0.0 V (Note 2)	-20	-90	mA						
lcc	Power Supply Current	All Inputs = GND,		COM, F			190				
	· ewer supply surrent	V _{CC} = Max.	VCC = Max. MIL				190	mA			
VI	Input Clamp Voltage	V _{CC} = Min., I _{IN} = -18 mA					-1.2	V			
4	Output Leakage Current	V _{CC} = Max.	COM'L	Vo = 5.0 V							
ICEX		G=2.4 V	MIL	Vo = Vcc			40	μА			
	7.1.			Vo = 0.4 V			-40	1 ~			
CIN	Input Capacitance	V _{CC} = 5.0 V, T _A = 25°C V _{IN} /V _{OUT} = 2.0 V at f = 1 MHz (Note 3)			· · · · ·	5					
Cout	Output Capacitance					8		pF			

Notes: 1. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

2. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.

3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance

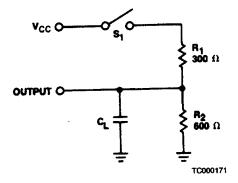
SWITCHING CHARACTERISTICS over operating range unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

No.	Parameter Symbol			Am27S49SA		Am27S49A		Am27S49		
		Parameter Description		Min.	Max.	Min.	Max.	Min.	Max.	Unit
		Address Valid to Output	COM'L		25		40		55	
1	TAVQV	Valid Access Time	MIL		30		55		65	ns
2	TGHOZ Enable V	Delay from Output Enable Valid to	COM, F		15		30		35	
		Output High Z	MIL		20		35		40	ns
3 TGLOV	TGLQV	Delay from Output Enable Valid to	COM'L		15		30		35	
	- Idear	Output Valid	MIL		20		35		40	ns

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V — See Switching Test Circuit diagram.

*Subgroups 7 and 8 apply to functional tests.

SWITCHING TEST CIRCUIT



- Notes: 1. TAVQV is tested with switch S_1 closed and $C_L = 50$ pF.
 - For three-state outputs, TGLOV is tested with C_L = 50 pF to the 1.5 V level; S₁ is open for high impedance to HIGH tests and closed for high impedance to LOW tests. TGHQZ is tested with C_L = 5 pF. HIGH to high impedance tests are made with S₁ open to an output voltage of Steady State HIGH = 0.5 V; LOW to high-impedance tests are made with S₁ closed to the Steady State LOW + 0.5 V level.

SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORMS

